

	<h2 style="color: red;">SI7945DP-T1-E3</h2>	
	Hersteller-Teilenummer:	SI7945DP-T1-E3
	Hersteller / Marke:	Vishay / Siliconix
	Teil der Beschreibung:	MOSFET 2P-CH 30V 7A PPAK SO-8
Datenblätter:	 SI7945DP-T1-E3.pdf	
RoHs Status:	Bleifrei / RoHS-konform	
Lagerzustand:	New original, 19638 pcs Stock Available.	
Liefern von:	Hong Kong	
Versandweg:	DHL/Fedex/TNT/UPS/EMS	
<p>Image may be representation. See specs for product details.</p>		

Spezifikationen

Teilenummer	SI7945DP-T1-E3
Hersteller	Vishay / Siliconix
Beschreibung	MOSFET 2P-CH 30V 7A PPAK SO-8
Kategorie	Diskrete Halbleiterprodukte > Transistoren-FETs,
Teilstatus	19638 pcs Stock
Serie	TrenchFET®
Betriebstemperatur	-55°C ~ 150°C (TJ)
Befestigungsart	Surface Mount
Leistung - max	1.4W
Verpackung / Gehäuse	PowerPAK® SO-8 Dual
Supplier Device-Gehäuse	PowerPAK® SO-8 Dual
Typ FET	2 P-Channel (Dual)
FET-Merkmal	Logic Level Gate
Drain-Source-Spannung (Vdss)	30V
Strom - Ununterbrochener Abfluss (Id) bei 25 ° C	7A
Rds On (Max) @ Id, Vgs	20 mOhm @ 10.9A, 10V
VGS (th) (Max) @ Id	3V @ 250µA
Gate Charge (Qg) (Max) @ Vgs	74nC @ 10V
Eingabekapazität (Ciss) (Max) @ Vds	-
Verpackung	Tape & Reel (TR)


































SI7945DP-T1-E3 ist neu im Original, Suche SI7945DP-T1-E3 Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie SI7945DP-T1-E3 Vishay / Siliconix mit Garantie und Vertrauen. Anfrage SI7945DP-T1-E3: Info@Y-IC.com

Sie können auch interessiert sein:

 <p>SI7946ADP-T1-GE3 Electro-Films (EFI) / Vishay MOSFET 2 N-CH 150V POWERPAK SO8</p>	 <p>SI7945DP-T1-GE3 Vishay / Siliconix MOSFET 2P-CH 30V 7A PPAK SO-8</p>	 <p>SI7942DP-T1-E3 Electro-Films (EFI) / Vishay MOSFET 2N-CH 100V 3.8A PPAK SO-8</p>	 <p>SI7945DP-T1-GE3 Electro-Films (EFI) / Vishay MOSFET 2P-CH 30V 7A PPAK SO-8</p>
 <p>SI7945DP-T1-E3 Electro-Films (EFI) / Vishay MOSFET 2P-CH 30V 7A PPAK SO-8</p>	 <p>SI7945DP SI SI7945DP SI</p>	 <p>SI7946DP SI SI7946DP SI</p>	 <p>SI7946ADP-T1-GE3 VISHAY VISHAY QFN8</p>

heiße Teile

Mehr

- | | | | | |
|---|---|---|---|---|
|  SI7913DN-T1-E3 |  SI7913DN-T1-E3 |  SI7913DN-T1-GE3 | D SI7913DN-T1-GE3 |  SI7922DN-T1-E3 |
|  SI7922DN-T1-E3 |  SI7922DN-T1-GE3 | D SI7922DN-T1-GE3 |  SI7923DN-T1-E3 |  SI7923DN-T1-E3 |
|  SI7923DN-T1-GE3 |  SI7923DN-T1-GE3 |  SI7938DP-T1-GE3 |  SI7938DP-T1-GE3 |  SI7940DP |
| D SI7940DP-T1-E3 |  SI7940DP-T1-E3 |  SI7941DP-T1-E3 |  SI7941DP-T1-GE3 |  SI7942DP |
|  SI7942DP-T1-E3 |  SI7942DP-T1-E3 |  SI7942DP-T1-GE3 |  SI7942DP-T1-GE3 |  SI7945DP-T1-E3 |
|  SI7946DP |  SI7946DP-T1-E3 | D SI7946DP-T1-E3 |  SI7948DP |  SI7948DP-T1-E3 |
|  SI7949DP-T1-GE3 | D SI7949DP-T1-GE3 |  SI7956DP-T1-GE3 |  SI7956DP-T1-GE3 |  SI7958DP |
|  SI7958DP-T1-E3 |  SI7958DP-T1-E3 |  SI7958DP-T1-GE3 |  SI7958DP-T1-GE3 |  SI7960DP-T1-E3 |
|  SI7960DP-T1-E3 |  SI7960DP-T1-GE3 |  SI7960DP-T1-GE3 | D SI7964DP |  SI7964DP-T1-GE3 |
|  SI7964DP-T1-GE3 |  SI7970DP |  SI7970DP-T1-E3 |  SI7980DP-T1-E3 |  SI7980DP-T1-E3 |

Contact us: Info@Y-IC.com

HINZUFÜGEN: Einheit A5-B5 Nr.509, 5 / F Sing Win Fabrikgebäude, 15-17 Shing Yip St, Kwun Tong, Kowloon, HongKong.

Copyright © 2019 YIC International Co., Limited